

# QUICKSWITCH® PRODUCTS HIGH-SPEED CMOS 20-BIT BUS SWITCH WITH FLOW-THRU PINOUT

IDTQS32X2861

### **FEATURES:**

- · Enhanced N channel FET with no inherent diode to Vcc
- 25 $\Omega$  series resistors for low noise
- · Undershoot clamp diodes on all switch and control inputs
- · Available in 48-pin QVSOP package

## **APPLICATIONS:**

- · Hot-swapping, hot-docking
- Voltage translation (5V to 3.3V)
- Power conservation
- · Capacitance reduction and isolation
- Bus isolation
- · Clock gating

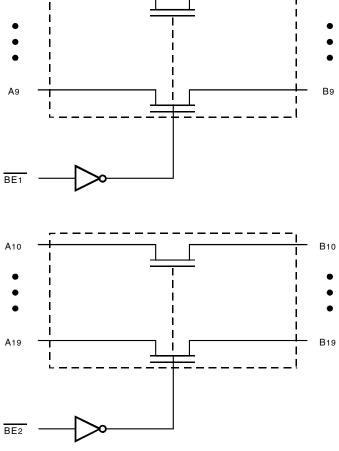
# **DESCRIPTION:**

The QS32X2861 provides two sets of ten high-speed CMOS TTL-compatible bus switches. The low ON resistance of the QS32X2861 allows inputs to be connected to outputs without adding propagation delay and without generating additional ground bounce noise. The QS32x2861 adds an internal  $25\Omega$  series termination resistor to each switch to reduce reflection noise in high-speed applications. The Bus Enable  $(\overline{\text{BEn}})$  signals turn the switches on.

The QS32X2861 bus switch is ideal for switching digital buses, as well as for hotplug buffering and 5V to 3V conversion.

The QS32X2861 is characterized for operation at -40°C to +85°C.

### FUNCTIONAL BLOCK DIAGRAM

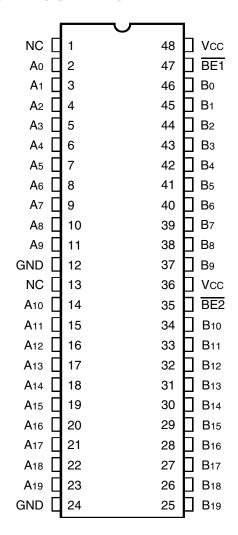


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INDUSTRIAL TEMPERATURE RANGE

MARCH 2002

### **PIN CONFIGURATION**



QVSOP TOP VIEW

### ABSOLUTE MAXIMUM RATINGS(1)

Symbol	Description	Max	Unit
VTERM <sup>(2)</sup>	Supply Voltage to Ground	-0.5 to +7	V
VTERM <sup>(3)</sup>	DC Switch Voltage Vs	-0.5 to +7	V
VTERM <sup>(3)</sup>	DC Input Voltage Vเง	-0.5 to +7	V
VAC	AC Input Voltage (pulse width ≤ 20ns)	-3	V
lout	DC Output Current	120	mA
Рмах	Maximum Power Dissipation (TA = 85°C)	0.5	W
Tstg	Storage Temperature	-65 to +150	°C

#### NOTE:

- 1. Stresses greater than those listed under ABSOLUTE MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.
- 2. Vcc terminals.
- 3. All terminals except Vcc.

# **CAPACITANCE**

 $(TA = +25^{\circ}C, f = 1.0MHz, VIN = 0V, VOUT = 0V)$ 

Pins	Тур.	Max. <sup>(1)</sup>	Unit
Control Pins	3	5	pF
Quickswitch Channels (Switch OFF)	5	7	pF

#### NOTE:

1. This parameter is measured at characterization but not tested.

### **PIN DESCRIPTION**

Pin Names	I/O	Description		
A0 - A19	I/O	Bus A		
Bo - B19	I/O	Bus B		
BEn I		Bus Enable		

#### FUNCTION TABLE(1)

BE1	BE2	A0 - A9	A10 - A19	Function
L	L	Bo - B9	B10 - B19	Connect
L	Н	Bo - B9	Z	Connect
Н	L	Z	B10 - B19	Connect
Н	Н	Z	Z	Disconnect

#### NOTE

- 1. H = HIGH Voltage Level
  - L = LOW Voltage Level
  - Z = High-Impedance

### DC ELECTRICAL CHARACTERISTICS OVER OPERATING RANGE

 $Following \ Conditions \ Apply \ Unless \ Otherwise \ Specified:$ 

Industrial: TA = -40°C to +85°C, VCC =  $5.0V \pm 5\%$ 

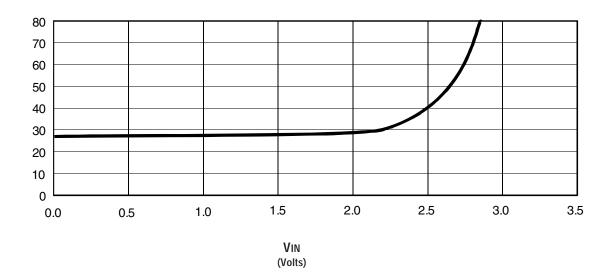
Symbol	Parameter	Test Conditions	Min.	Typ. <sup>(1)</sup>	Max.	Unit
VIH	Input HIGH Level	Guaranteed Logic HIGH for Control Pins	2	_	_	V
VIL	Input LOW Level	Guaranteed Logic LOW for Control Pins	_	_	0.8	V
lin	Input LeakageCurrent (Control Inputs) <sup>(2)</sup>	$0V \le VIN \le VCC$	_	±0.01	±1	μA
loz	Off-State Output Current (Hi-Z)	0V ≤ Vouт ≤ Vcc, Switches OFF	_	±0.01	±1	μA
Ron <sup>(3)</sup>	Switch ON Resistance	Vcc = Min., Vin = 0V, Ion = 30mA	15	20	35	Ω
		VCC = Min., $VIN = 2.4V$ , $ION = 15mA$	18	25	40	
VP	Pass Voltage <sup>(2)</sup>	$V_{IN} = V_{CC} = 5V$ , $I_{OUT} = -5\mu A$	3.7	4	4.2	V

#### NOTES:

- 1. Typical values are at Vcc = 5.0V, TA = 25°C.
- 2. Pass Voltage is guaranteed but not production tested.
- 3. Rout changed on March 8, 2002. See rear page for more information.

# TYPICAL ON RESISTANCE vs Vin AT Vcc = 5V





### POWER SUPPLY CHARACTERISTICS

Symbol	Parameter	Test Conditions <sup>(1)</sup>	Typ <sup>(2)</sup>	Max.	Unit
Icco	Quiescent Power Supply Current	Vcc = Max., Vin = GND or Vcc, f = 0	0.2	6	μΑ
Δlcc	Power Supply Current per Control Input HIGH <sup>(3)</sup>	Vcc = Max., Vin = 3.4V, f = 0	_	2.5	mA
ICCD	Dynamic Power Supply Current per MHz <sup>(4)</sup>	Vcc = Max., A and B pins open  BEn Control Input Toggling at 50% Duty Cycle	_	0.25	mA/MHz

#### NOTES:

- 1. For conditions shown as Min. or Max., use the appropriate values specified under DC Electrical Characteristics.
- 2. Typical values are at Vcc = 5.0V, 25°C ambient.
- 3. Per TLL driven input ( $V_{IN} = 3.4V$ , control inputs only). A and B pins do not contribute to  $\Delta lcc$ .
- 4. This current applies to the control inputs only and represents the current required to switch internal capacitance at the specified frequency. The A and B pins generate no significant AC or DC currents as they transition. This parameter is guaranteed but not production tested.

### SWITCHING CHARACTERISTICS OVER OPERATING RANGE

 $TA = -40^{\circ}C \text{ to } +85^{\circ}C, VCC = 5.0V \pm 5\%;$ 

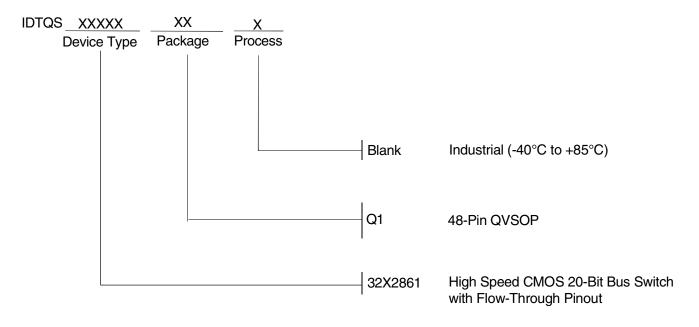
CLOAD = 50pF, RLOAD =  $500\Omega$  unless otherwise noted.

Symbol	Parameter	Min. <sup>(1)</sup>	Тур.	Max.	Unit
tplh	Data Propagation Delay (2,3)	_	1.25	_	ns
tphl	An to/from Bn				
tpzh	Switch Turn-on Delay	1.5	_	7.5	ns
tpzl	BEn to An/Bn				
tphz	Switch Turn-off Delay (2)	1.5	_	6.5	ns
tplz	BEn to An/Bn				

#### NOTES:

- Minimums are guaranteed but not production tested.
- 2. This parameter is guaranteed but not production tested.
- 3. The bus switch contributes no propagation delay other than the RC delay of the ON resistance of the switch and the load capacitance. The time constant for the switch alone is of the order of 1.25ns for C<sub>L</sub> = 50pF. Since this time constant is much smaller than the rise and fall times of typical driving signals, it adds very little propagation delay to the system. Propagation delay of the bus switch, when used in a system, is determined by the driving circuit on the driving side of the switch and its interaction with the load on the driven side.

### ORDERING INFORMATION



As per PCN L0201-02, the Output Resistance (Ron) specifications have changed as of March 8, 2002. The original specifications were:

Parameter	Description	Min.	Тур.	Max.	Unit
Ron	VCC = Min, VIN = 0V, ION = 30mA		28	35	Ω
	VCC = Min, VIN = 2.4V, ION = 15mA	_	35	40	

